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Correction: Role of annealing temperature on the sol–gel synthesis of VO₂ nanowires with *in situ* characterization of their metal–insulator transition

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Correction for 'Role of annealing temperature on the sol–gel synthesis of VO₂ nanowires with *in situ* characterization of their metal–insulator transition' by Y.-R. Jo *et al.*, *RSC Adv.*, 2018, 8, 5158–5165.

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